LMV358

DESCRIPTION

The LMV358(dual) are rail- to- rail input and output voltage feedback amplifiers offering low cost. They have a wide input common -mode voltage range and output voltages wing,and take the minimum operating supply voltage down to 2.1V and the maximum recommended supply voltage is 5.5V. temperature range.

The LMV358 provide 1MHz bandwidth at a low c urrent consumption of 60μA per amplifier. Very low input bias currents of 10p A enable LMV358 to be used for integrators, photodiode amplifiers, and piezoelectric sensors. Rail - to -rail inputs and outputs are useful to designers buffering ASIC in single - supply systems. Applications for the series amplifiers include safety monitoring , portable equipment, battery and power supply control, and signal conditioning and interfacing for transducers in very low power systems. The LMV358 is available in SOP8and MSOP8 packages.

SOP-8

Features

- Low Cost
- Rail- to- Rail Input and Output
- 0.8mV Typical VOS
- Unity Gain Stable
- Gain Bandwidth Product: 1MHz
- Very Low Input Bias Currents:
- Operates on 2.1V to 5.5V Supplies
- Input Voltage Range: - 0.1V to +5.6V with VS = 5.5V
- Low Supply Current: < 60μA/Amplifier
- Small Packaging：LMV358 Available in SOP8, MSOP8

Applications

- ASIC Input or Output Amplifier
- Sensor Interface
- Piezo Electric Transducer Amplifier
- Medical Instrumentation
- Mobile Communication
- Audio Output
- Portable Systems
- Smoke Detectors
- Notebook PC
- PCMCIA Cards
- Battery – Powered Equipment
- DSP Interface

LMV358 ELECTRICAL CHARACTERISTICS

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V+ to V V
Common-Mode Input Voltage. .....($-V_S$) - 0.5V to ($+V_S$) + 0.5V
Storage Temperature Range.....–65˚C to +150˚C
Junction Temperature.....160˚C
Operating Temperature Range.....-40˚C to +85˚C
Lead Temperature Range (Soldering 10 sec).....260˚C

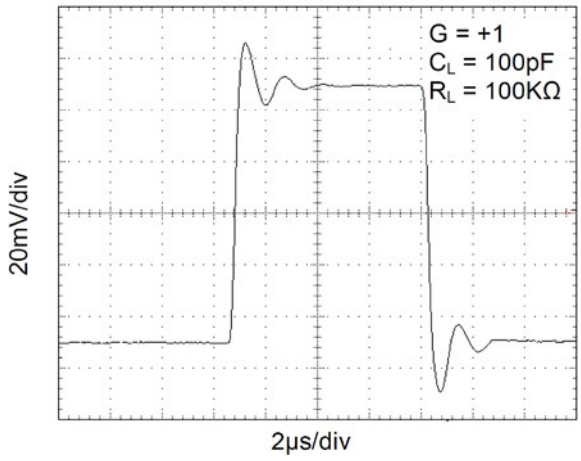
(At RL = 100KΩ connected to Vs/2, and VOUT = Vs/2, V_S=+5V,unless otherwise noted.)

PARAMETER	CONDITIONS	LMV358				
		TYP	MIN/MAX OVER TEMPERATURE			
		+25°C	+25°C	0°C to 75°C	UNITS	MIN/MAX
INPUT HARACTERISTICS						
Input Offset Voltage (VOS)		±0.8	±5	±6	mV	MAX
Input Bias Current (IB)		10			pA	TYP
Input Offset Current (IOS)		10			pA	TYP
Common-Mode Voltage Range (VCM)	VS=5.5V	-0.1to+5.6			V	TYP
Common-Mode Rejection Ratio (CMRR)	VS=5.5V, VCM=-0.1V to 4V	70	62	62	dB	MIN
	VS= 5.5V, VCM=-0.1V to 5.6V	68	56	55	dB	MIN
Open-Loop Voltage Gain (AOL)	RL= 5KΩ ,Vo=0.1V to 4.9V	80	70	70	dB	MIN
	RL=100KΩ,Vo=0.035V to 4.965V	84	80	80	dB	MIN
OUTPUT CHARACTERISTICS						
Output Voltage Swing from Rail	RL = 100KΩ	0.008			V	TYP
Output Current (IOUT)	RL = 10KΩ	0.08			V	TYP
		27	20	18.8	mA	MIN
POWER SUPPLY						
Operating Voltage Range			2.1	2.5	V	MIN
			5.5	5.5	V	MAX
Power Supply Rejection Ratio (PSRR)	Vs =+2.5V to + 5.5V VCM= (-VS) + 0.5V	82	60	58	dB	MIN
Quiescent Current / Amplifier (IQ)	IOUT = 0	60	80	86	μA	MAX
DYNAMIC PERFORMANCE						
Gain-Bandwidth Product (GBP)	CL= 100pF	1			MHz	TYP
Slew Rate (SR)	G = +1, 2V Output Step	0.52			V/μs	TYP
Settling Time to 0.1% (tS)	G = +1, 2V Output Step	5.3			μs	TYP
Overload Recovery Time	VIN ·Gain = VS	2.6			μs	TYP
NOISE PERFORMANCE						
Voltage Noise Density (en)	f = 1kHz	27			$n\sqrt{Hz}$	TYP
	f = 10kHz	20			$n\sqrt{Hz}$	TYP

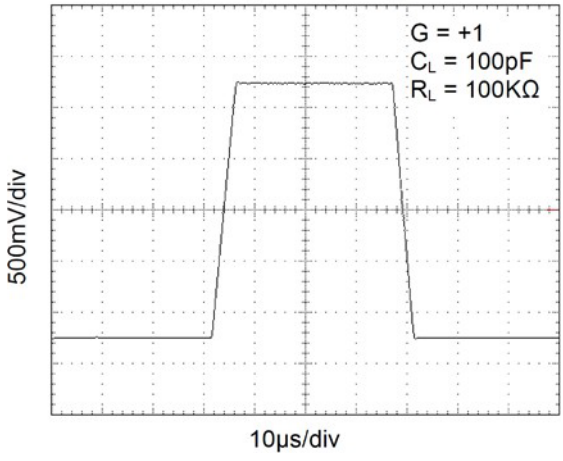
TYPICAL PERFORMANCE CHARACTERISTICS

At T_A = +25°C, V_S = +5V, and R_L = 100KΩ connected to Vs/2, unless otherwise noted.

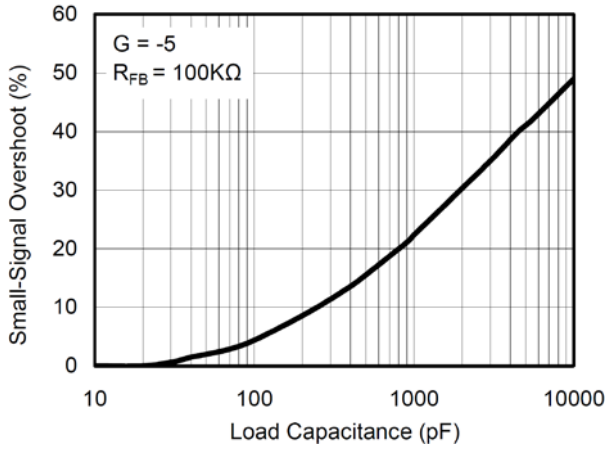
Small-Signal Step Response



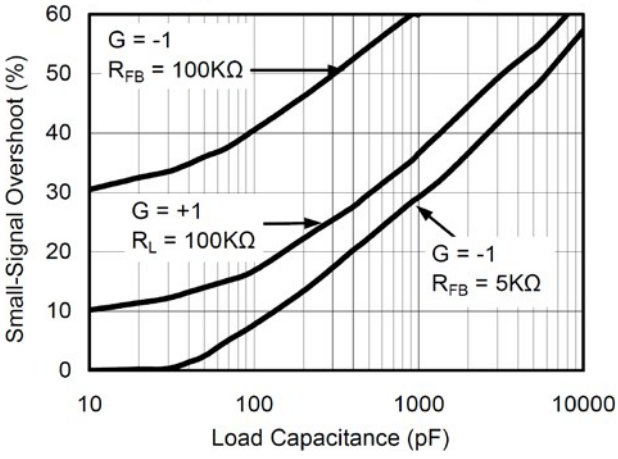
Large-Signal Step Response



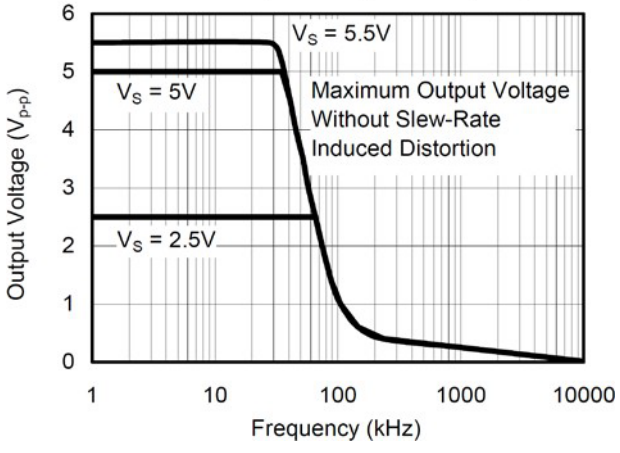
Small-Signal Overshoot vs. Load Capacitance



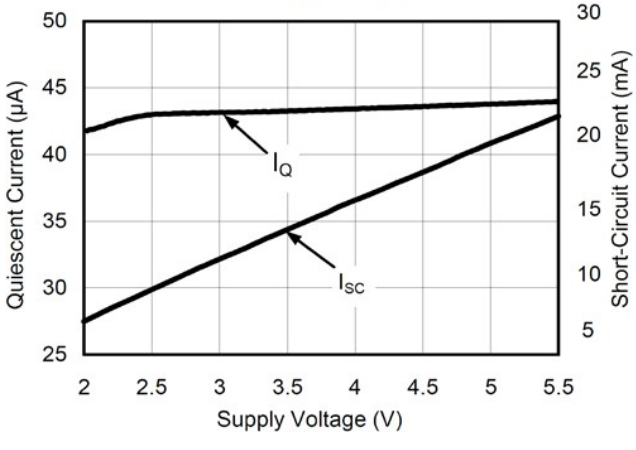
Small-Signal Overshoot vs. Load Capacitance

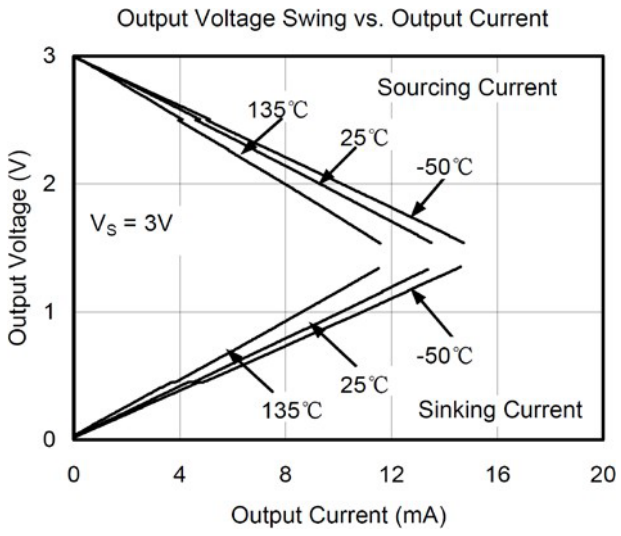


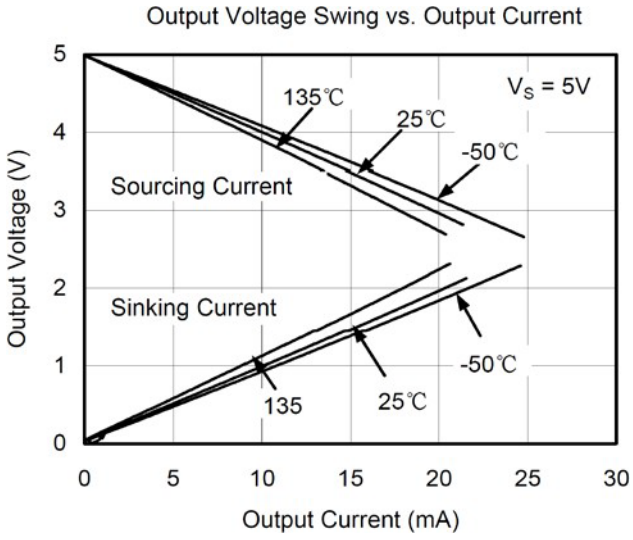
Maximum Output Voltage vs. Frequency



Quiescent and Short-Circuit Current vs. Supply Voltage

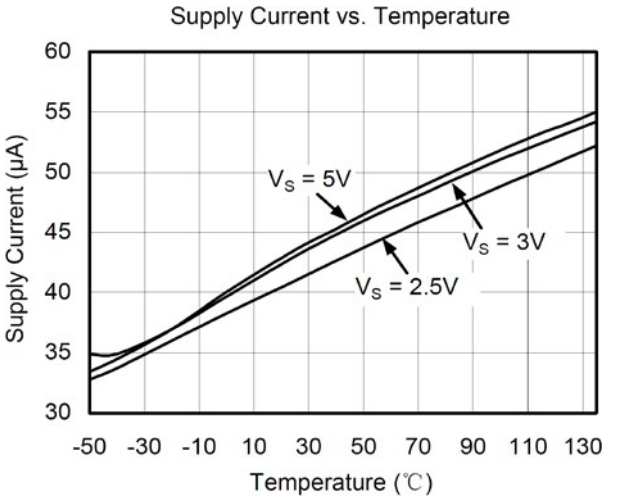


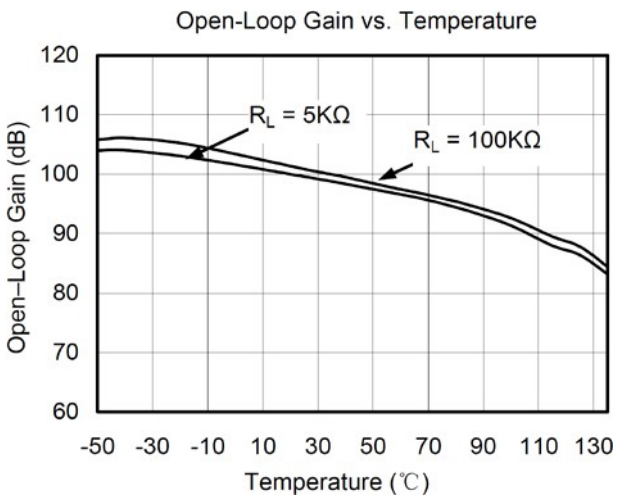


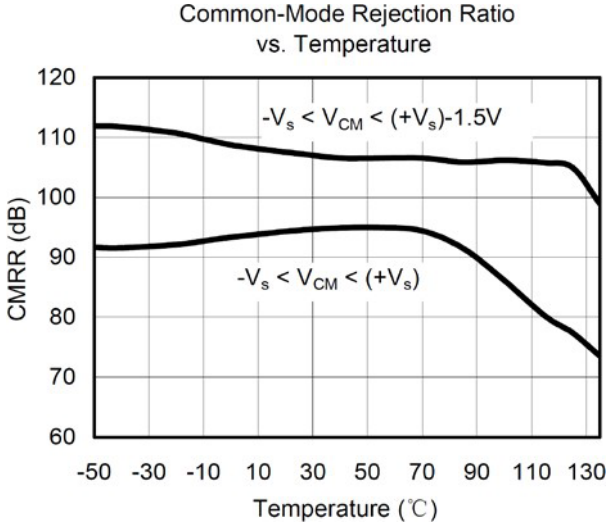


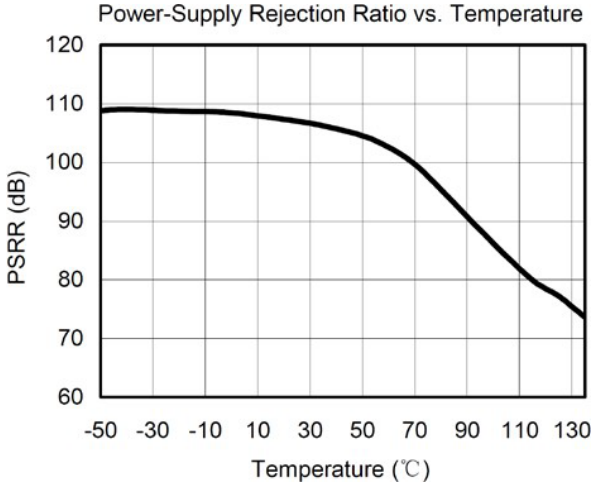
TYPICAL PERFORMANCE CHARACTERISTICS

At TA = +25℃, VS = +5V, and RL = 100KΩ connected to Vs/2, unless otherwise noted.









Power-Supply Bypassing and Layout

The LMV358 family operates from either a single +2.5V to +5.5V supply or dual ±1.25V to ±2.75V supplies. For single-supply operation, bypass the power supply VDD with a 0.1μF ceramic capacitor which should be placed close to the VDD pin. For dual-supply operation, both the VDD and the VSS supplies should be bypassed to ground with separate 0.1μF ceramic capacitors. 2.2μF tantalum capacitor can be added for better performance.

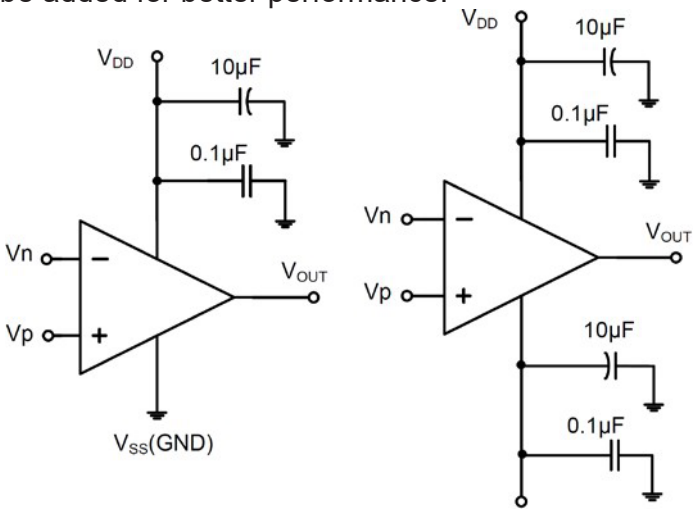


Figure 3. Amplifier with Bypass Capacitors

TYPICAL APPLICATION CIRCUITS

Differential Amplifier

The circuit shown in Figure 4 performs the difference function. If the resistors ratios are equal (R4 / R3 = R2 / R1), then VOUT = (Vp – Vn) × R2 / R1 + VREF.

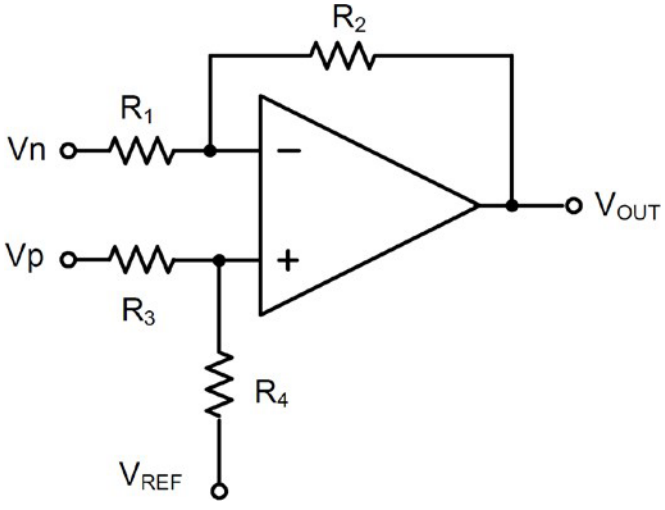


Figure 4. Differential Amplifier

Instrumentation Amplifier

The circuit in Figure 5 performs the same function as that in Figure 4 but with the high input impedance.

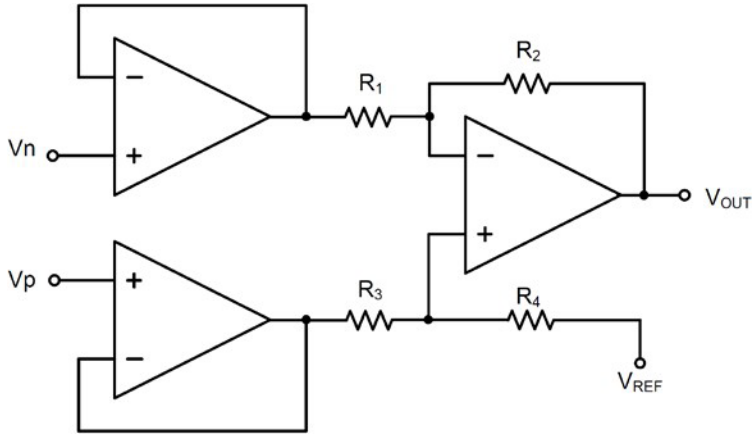


Figure 5. Instrumentation Amplifier

Low Pass Active Filter

The low pass filter shown in Figure 6 has a DC gain of (-R2 / R1) and the –3dB corner frequency is 1/2πR2C. Make sure the filter is within the bandwidth of the amplifier. The Large values of feedback resistors can couple with parasitic capacitance and cause undesired effects such as ringing or oscillation in high-speed amplifiers. Keep resistors value as low as possible and consistent with output loading consideration.

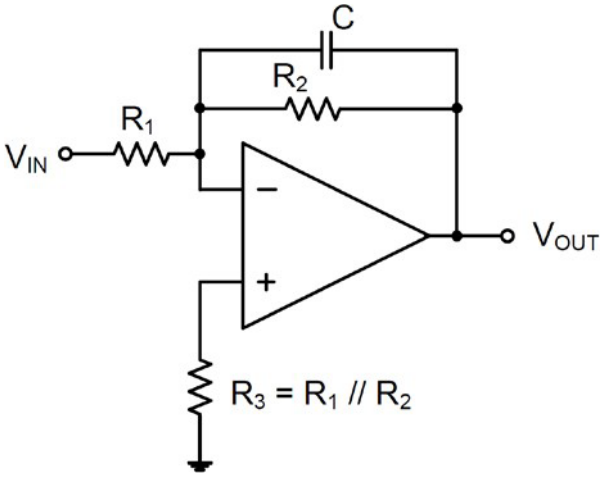
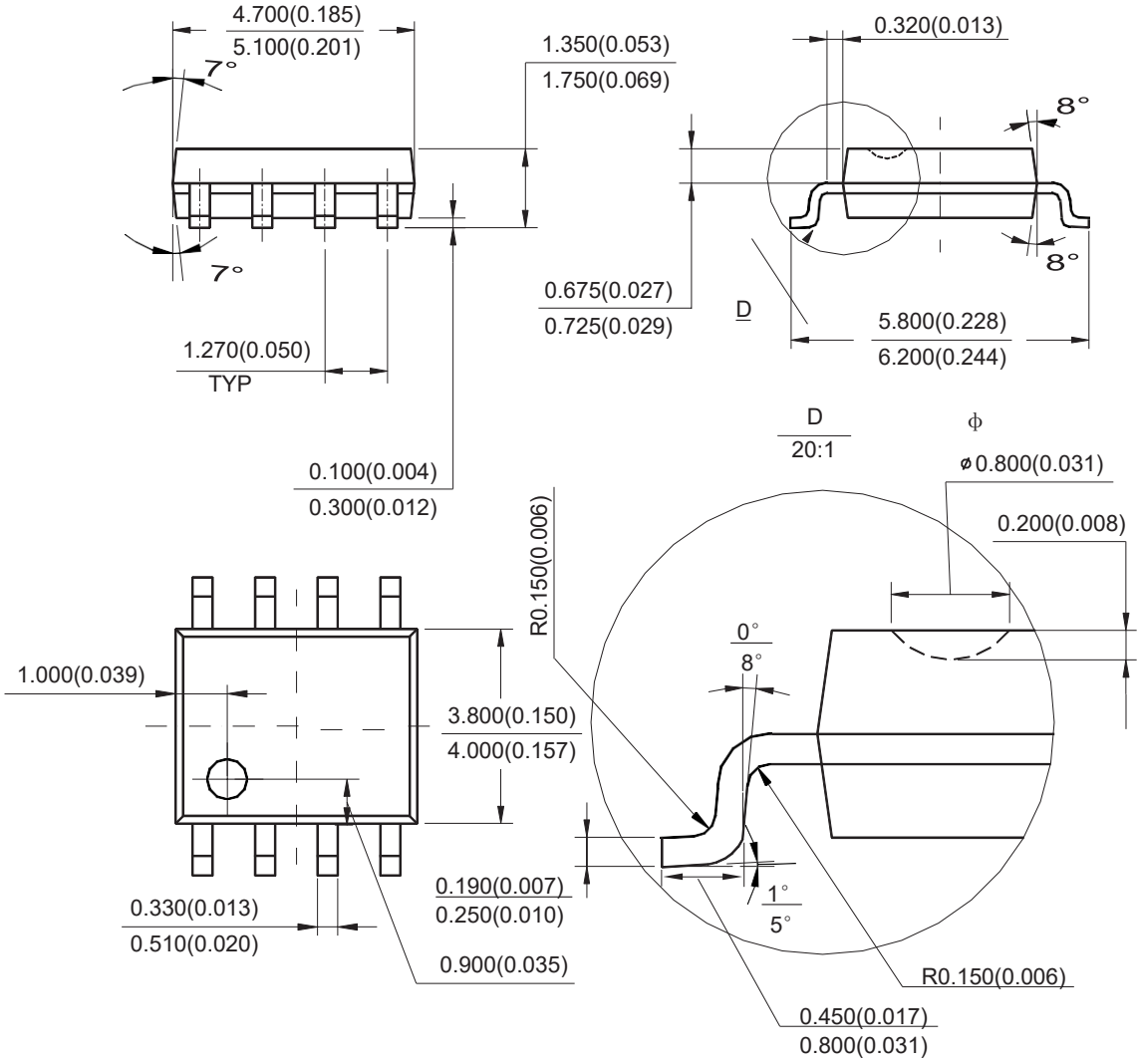


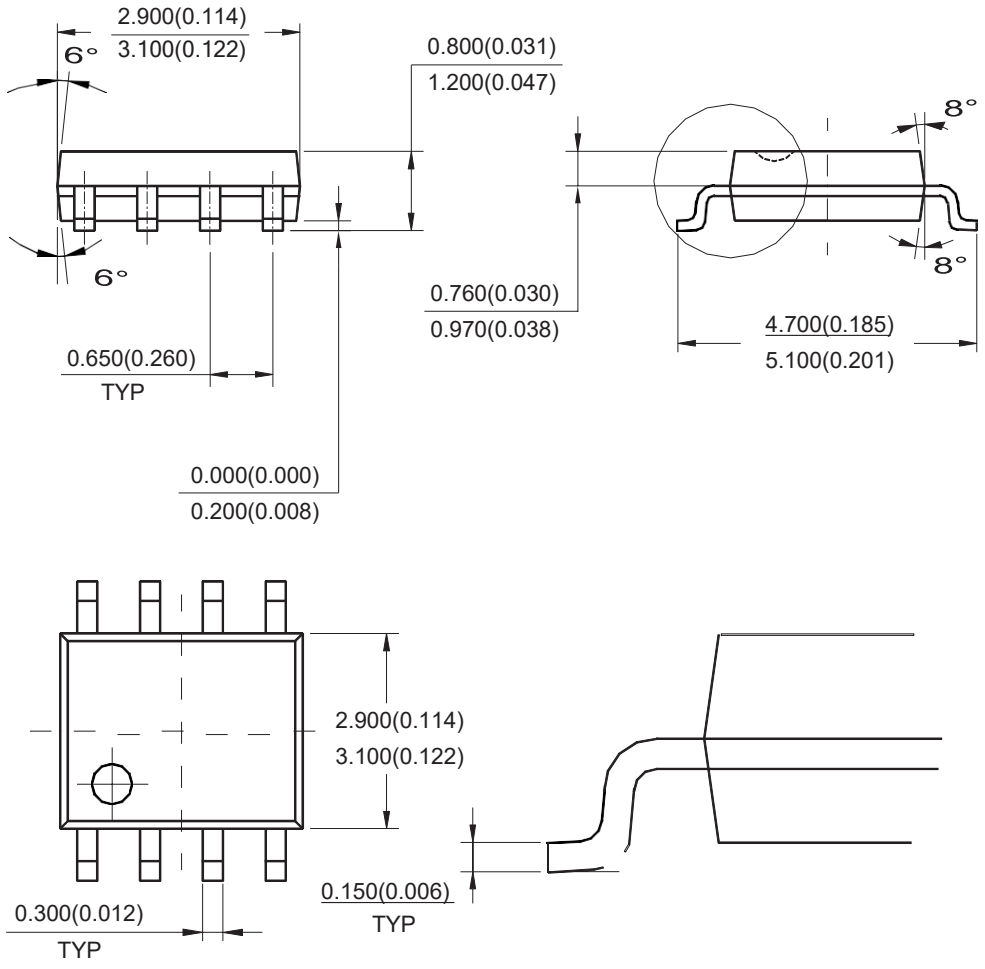
Figure 6. Low Pass Active Filter

Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.

Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.